



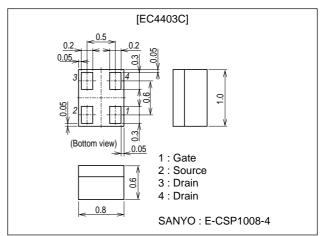
# **Small Signal Switch, Interface Applications**

### **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

## **Package Dimensions**

unit : mm 2197



# **Specifications**

## Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		50	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		0.1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	0.4	Α
Allowable Power Dissipation	PD		0.15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

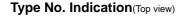
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	50			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =50V, V <sub>GS</sub> =0			10	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±16V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =100μA	1		2.4	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =50mA	85	120		mS
Static Drain-to-Source On-State Resistance	RDS(on)1	I <sub>D</sub> =50mA, V <sub>GS</sub> =10V		5.8	7.5	Ω
	RDS(on)2	ID=30mA, VGS=4V		7.5	10.5	Ω

Continued on next page.

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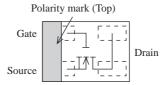
Parameter	Symbol	Conditions	Ratings			- Unit
	Symbol		min	typ	max	Uill
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		6.2		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		4.4		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		1.5		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		10		ns
Rise Time	t <sub>r</sub>	See specified Test Circuit.		11		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		105		ns
Fall Time	tf	See specified Test Circuit.		75		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =100mA		1.40		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =100mA		0.21		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =100mA		0.34		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =100mA, V <sub>GS</sub> =0		0.9	1.2	٧



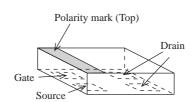


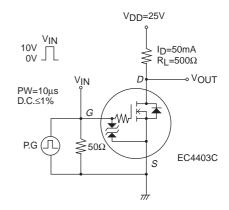
## **Switching Time Test Circuit**

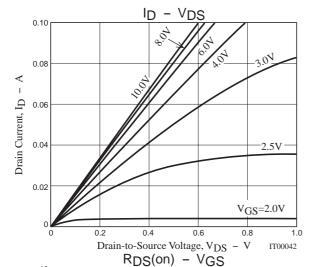


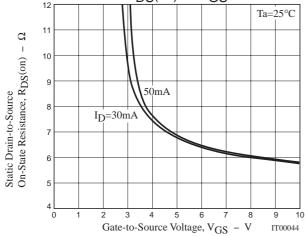


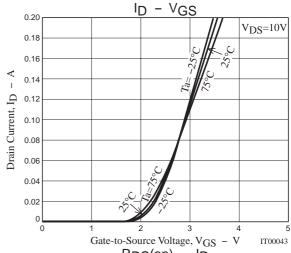
\*Electrodes: on the bottom

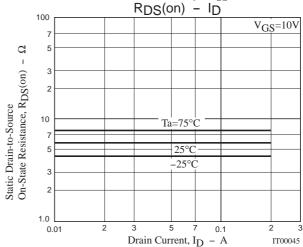


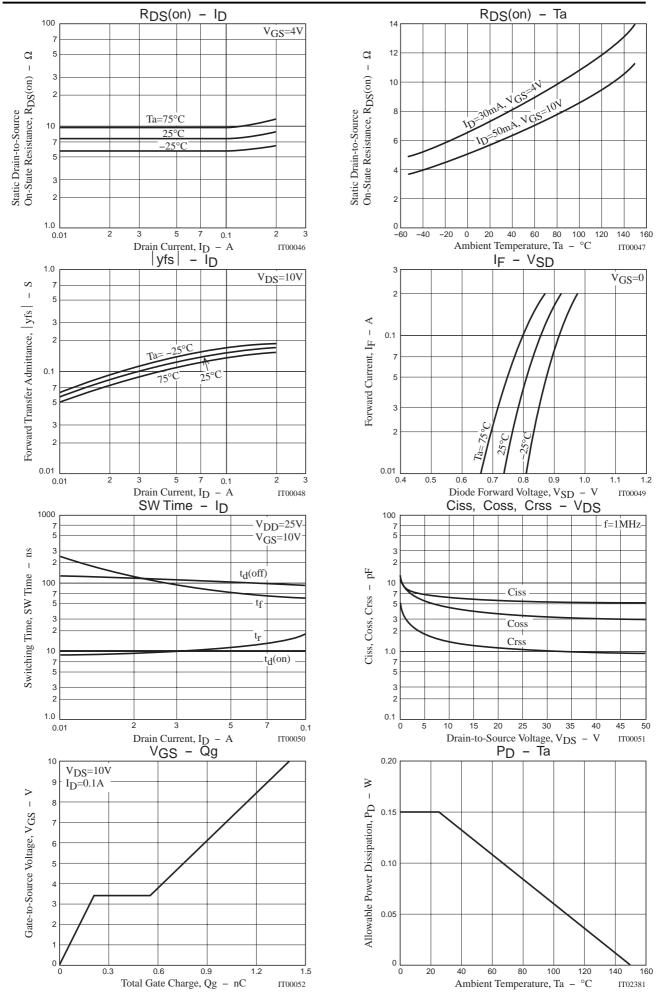












Note on usage: Since the EC4403C is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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